

Electrical DC Characteristics

T_{amb} = 25 °C, unless otherwise specified

Parameter	Test condition	Symbol	Min	Typ.	Max	Unit
Collector-emitter cut-off current	V _{CE} = 20 V, V _{BE} = 0	I _{CES}			100	μA
Collector-base cut-off current	V _{CB} = 20 V, I _E = 0	I _{CBO}			100	nA
Emitter-base cut-off current	V _{EB} = 2 V, I _C = 0	I _{EBO}			10	μA
Collector-emitter breakdown voltage	I _C = 1 mA, I _B = 0	V _{(BR)CEO}	15			V
DC forward current transfer ratio	V _{CE} = 10 V, I _C = 14 mA	h _{FE}	25	50	150	

Electrical AC Characteristics

T_{amb} = 25 °C, unless otherwise specified

Parameter	Test condition	Symbol	Min	Typ.	Max	Unit
Transition frequency	V _{CE} = 10 V, I _C = 14 mA, f = 500 MHz	f _T		5		GHz
Collector-base capacitance	V _{CB} = 10 V, f = 1 MHz	C _{cb}		0.35		pF
Collector-emitter capacitance	V _{CE} = 10 V, f = 1 MHz	C _{ce}		0.3		pF
Emitter-base capacitance	V _{EB} = 0.5 V, f = 1 MHz	C _{eb}		1.3		pF
Noise figure	V _{CE} = 10 V, I _C = 2 mA, f = 500 MHz, Z _S = 50 Ω	F		2.2		dB
Power gain	V _{CE} = 10 V, I _C = 14 mA, Z _L = Z _{Lopt} , f = 500 MHz	G _{pe}		19.5		dB
	V _{CE} = 10 V, I _C = 14 mA, Z _L = Z _{Lopt} , f = 800 MHz	G _{pe}		14		dB
Linear output voltage - two tone intermodulation test	V _{CE} = 10 V, I _C = 14 mA, d _{IM} = 60 dB, f ₁ = 806 MHz, f ₂ = 810 MHz, Z _S = Z _L = 50 Ω	V ₁ = V ₂		100		mV
Third order intercept point	V _{CE} = 10 V, I _C = 14 mA, f = 800 MHz	IP ₃		23		dBm

Common Emitter S-Parameters

$Z_0 = 50 \Omega$, $T_{amb} = 25^\circ\text{C}$, unless otherwise specified

V_{CE}/V	I_C/mA	f/MHz	S11		S21		S12		S22	
			LIN MAG	ANG	LIN MAG	ANG	LIN MAG	ANG	LIN MAG	ANG
				deg		deg		deg		deg
5	2	100	0.82	-27.8	6.31	155.8	0.03	73.8	0.95	-10.2
		300	0.59	-72.7	4.66	121.6	0.06	54.0	0.80	-22.1
		500	0.41	-107.7	3.49	99.9	0.08	46.7	0.70	-27.0
		800	0.30	-154.9	2.474	78.0	0.10	44.9	0.63	-32.3
		1000	0.29	176.7	2.08	66.9	0.11	46.2	0.60	-36.3
		1200	0.30	153.2	1.80	56.4	0.12	47.6	0.57	-40.6
		1500	0.35	126.8	1.50	43.1	0.15	48.9	0.54	-47.6
		1800	0.41	108.7	1.32	31.2	0.18	49.2	0.50	-55.5
5	5	2000	0.45	99.1	1.22	24.4	0.20	48.0	0.48	-61.1
		100	0.65	-39.9	12.44	145.2	0.02	70.3	0.88	-16.2
		300	0.35	-91.8	7.26	108.3	0.05	58.7	0.65	-25.4
		500	0.22	-130.4	4.85	90.2	0.07	58.5	0.57	-26.9
		800	0.16	177.4	3.22	72.6	0.10	58.2	0.52	-30.6
		1000	0.18	150.9	2.66	63.4	0.12	57.3	0.50	-34.5
		1200	0.21	131.6	2.28	54.4	0.14	55.5	0.47	-38.6
		1500	0.27	112.7	1.89	42.8	0.18	51.9	0.44	-45.2
5	10	1800	0.33	100.1	1.65	31.8	0.21	48.2	0.40	-52.1
		2000	0.37	92.8	1.53	25.2	0.24	45.0	0.38	-56.9
		100	0.45	-54.6	18.55	133.7	0.02	70.4	0.79	-21.5
		300	0.19	-112.5	8.73	99.4	0.04	66.6	0.55	-24.7
		500	0.12	-156.4	5.54	84.5	0.07	66.8	0.49	-24.9
		800	0.12	148.7	3.60	69.5	0.11	64.0	0.46	-28.7
		1000	0.15	129.3	2.96	61.3	0.13	61.4	0.44	-32.8
		1200	0.18	117.0	2.51	53.0	0.16	58.0	0.42	-37.1
5	14	1500	0.24	104.4	2.08	42.1	0.19	52.8	0.38	-43.5
		1800	0.30	94.9	1.82	31.8	0.23	47.7	0.35	-49.9
		2000	0.34	89.5	1.67	25.4	0.25	43.7	0.32	-54.5
		100	0.35	-62.6	20.95	128.4	0.02	71.4	0.73	-23.2
		300	0.14	-124.4	9.11	96.3	0.04	70.1	0.51	-23.7
		500	0.10	-173.0	5.71	82.7	0.07	69.3	0.47	-23.7
		800	0.12	138.3	3.70	68.2	0.11	65.5	0.44	-27.7
		1000	0.15	123.3	3.03	60.4	0.13	62.5	0.42	-32.1
5	20	1200	0.18	113.2	2.58	52.3	0.16	58.7	0.40	-36.5
		1500	0.24	101.6	2.13	41.7	0.20	52.8	0.36	-42.9
		1800	0.30	93.2	1.85	31.4	0.23	47.4	0.33	-49.2
		2000	0.33	88.4	1.72	25.0	0.26	43.3	0.30	-53.6
		100	0.26	-71.1	22.95	123.4	0.01	72.4	0.68	-23.9
		300	0.11	-140.3	9.39	93.8	0.04	73.2	0.49	-22.0
		500	0.09	169.9	5.84	81.1	0.07	71.5	0.46	-22.0
		800	0.13	131.1	3.75	67.3	0.11	66.9	0.43	-26.7
5	20	1000	0.15	117.8	3.07	59.7	0.14	63.3	0.42	-31.0
		1200	0.18	109.5	2.62	51.7	0.16	59.3	0.39	-35.4
		1500	0.24	99.5	2.16	41.1	0.20	53.3	0.36	-41.8
		1800	0.30	93.1	1.87	30.9	0.24	47.7	0.32	-48.1
		2000	0.33	87.9	1.73	24.8	0.26	43.4	0.30	-52.4

V_{CE}/V	I_C/mA	f/MHz	S11		S21		S12		S22	
			LIN MAG	ANG	LIN MAG	ANG	LIN MAG	ANG	LIN MAG	ANG
				deg		deg		deg		deg
10	2	100	0.84	-25.7	6.21	157.1	0.02	74.8	0.96	-8.3
		300	0.61	-68.0	4.69	123.8	0.05	56.2	0.84	-18.4
		500	0.42	-101.2	3.57	102.1	0.07	49.3	0.75	-22.7
		800	0.28	-147.9	2.53	80.4	0.08	48.1	0.69	-27.8
		1000	0.26	-177.6	2.14	69.5	0.09	50.0	0.67	-31.6
		1200	0.27	156.2	1.84	59.0	0.11	51.9	0.65	-35.6
		1500	0.32	127.9	1.54	46.0	0.13	54.1	0.62	-41.9
		1800	0.39	109.1	1.34	34.2	0.15	55.0	0.59	-48.8
		2000	0.43	98.7	1.24	27.3	0.18	54.2	0.57	-53.8
10	5	100	0.67	-36.6	12.62	146.6	0.02	71.9	0.91	-13.0
		300	0.36	-83.1	7.54	110.1	0.04	60.7	0.72	-20.7
		500	0.21	-116.9	5.07	91.8	0.06	60.6	0.65	-22.2
		800	0.13	-173.7	3.37	74.5	0.08	61.0	0.61	-26.3
		1000	0.14	153.1	2.78	65.5	0.10	60.5	0.59	-29.8
		1200	0.17	130.1	2.37	56.7	0.12	59.0	0.57	-33.6
		1500	0.23	110.4	1.97	45.3	0.15	56.1	0.54	-39.7
		1800	0.29	97.7	1.71	34.6	0.18	53.1	0.51	-45.7
		2000	0.33	91.2	1.58	28.0	0.20	50.3	0.49	-50.0
10	10	100	0.49	-47.6	18.87	135.7	0.02	71.4	0.83	-16.8
		300	0.19	-93.8	9.12	101.1	0.04	68.0	0.63	-19.6
		500	0.09	-133.4	5.82	86.1	0.06	68.4	0.58	-20.2
		800	0.07	151.2	3.77	71.2	0.09	66.5	0.56	-24.4
		1000	0.10	124.5	3.09	63.3	0.11	64.3	0.54	-28.2
		1200	0.14	109.4	2.63	55.2	0.13	61.4	0.52	-32.2
		1500	0.19	98.6	2.17	44.7	0.16	56.9	0.49	-38.0
		1800	0.26	90.8	1.89	34.6	0.20	52.4	0.46	-44.1
		2000	0.29	86.0	1.75	28.3	0.22	48.9	0.44	-48.0
10	14	100	0.39	-53.4	21.53	130.3	0.01	72.2	0.79	-17.8
		300	0.13	-98.6	9.58	97.8	0.04	71.0	0.60	-18.5
		500	0.06	-146.3	6.02	84.0	0.06	70.7	0.57	-19.2
		800	0.07	131.1	3.89	70.0	0.09	67.8	0.55	-23.7
		1000	0.10	113.4	3.18	62.4	0.11	65.3	0.53	-27.4
		1200	0.13	103.2	2.70	54.7	0.14	62.0	0.51	-31.5
		1500	0.19	94.2	2.23	44.3	0.17	57.0	0.48	-37.4
		1800	0.24	89.1	1.93	34.2	0.20	52.3	0.45	-43.3
		2000	0.29	85.3	1.79	28.13	0.22	48.6	0.43	-47.3

Typical Characteristics ($T_{amb} = 25^{\circ}\text{C}$ unless otherwise specified)

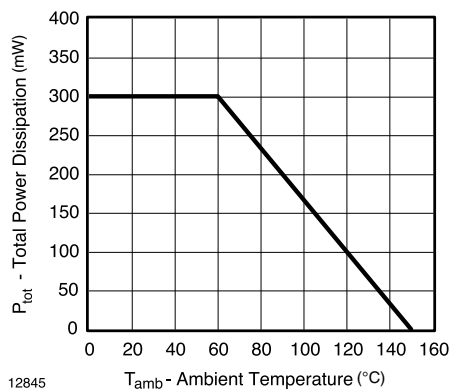


Figure 1. Total Power Dissipation vs. Ambient Temperature

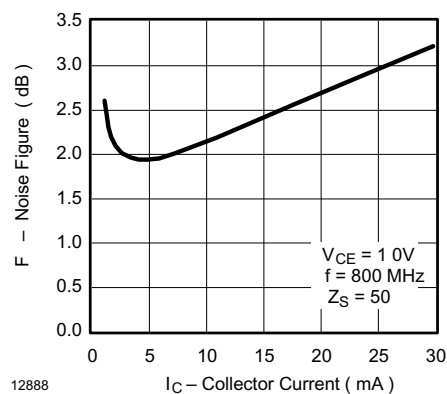


Figure 4. Noise Figure vs. Collector Current

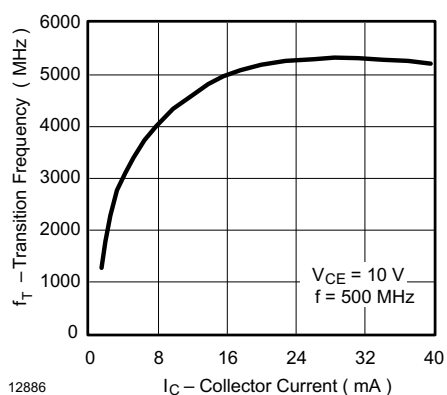


Figure 2. Transition Frequency vs. Collector Current

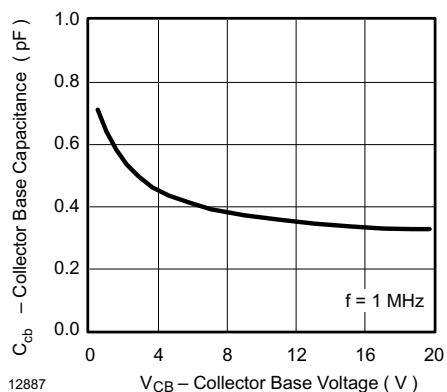


Figure 3. Collector Base Capacitance vs. Collector Base Voltage



$V_{CE} = 10\text{ V}$, $I_C = 14\text{ mA}$, $Z_0 = 50\text{ }\Omega$
 S_{11}

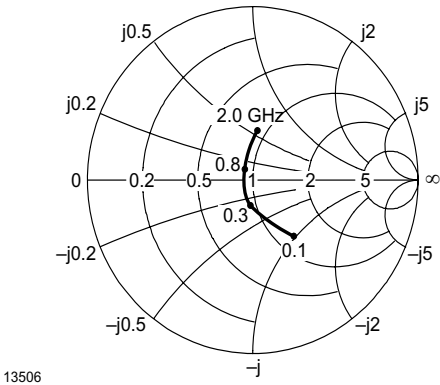


Figure 5. Input Reflection Coefficient

S_{21}

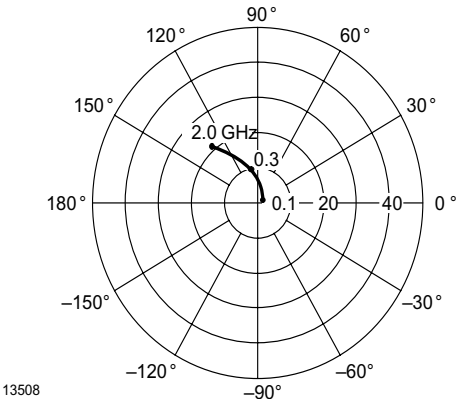


Figure 7. Forward Transmission Coefficient

S_{12}

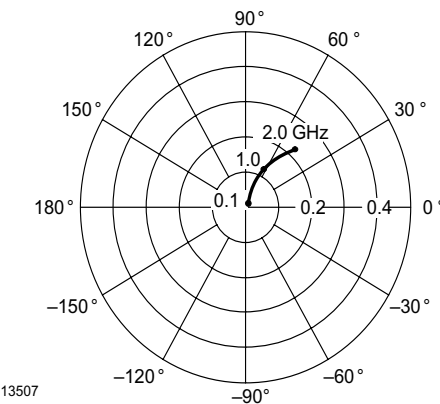


Figure 6. Reverse Transmission Coefficient

S_{22}

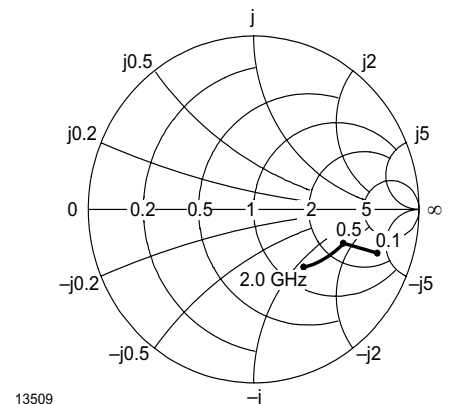
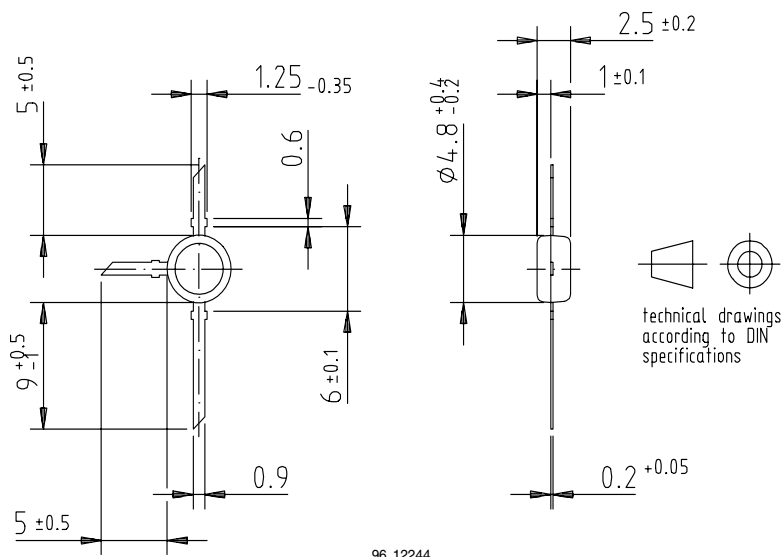


Figure 8. Output Reflection Coefficient

Package Dimensions in mm



Ozone Depleting Substances Policy Statement

It is the policy of Vishay Semiconductor GmbH to

1. Meet all present and future national and international statutory requirements.
2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

Vishay Semiconductor GmbH has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively
2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA
3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

Vishay Semiconductor GmbH can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

We reserve the right to make changes to improve technical design
and may do so without further notice.

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Vishay Semiconductor GmbH, P.O.B. 3535, D-74025 Heilbronn, Germany



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